Low-Voltage 1:5 Dual Diff. LVECL/LVPECL/LVEPECL/HSTL Clock Driver

The MC100LVEP210 is a low skew 1–to–5 dual differential driver, designed with clock distribution in mind. The LVECL/LVPECL input signals can be either differential or single–ended if the $V_{\rm BB}$ output is used. The signal is fanned out to 5 identical differential outputs. HSTL inputs can be used when the EP210 is operating in LVPECL mode.

The LVEP210 specifically guarantees low output-to-output skew. Optimal design, layout, and processing minimize skew within a device and from lot to lot.

To ensure the tight skew specification is realized, both sides of the differential output need to be terminated identically into 50Ω even if only one side is being used. When fewer than all ten pairs are used, identically terminate all the output pairs on the same package side whether used or unused. If no outputs on a single side are used, then leave these outputs open (unterminated). This will maintain minimum output skew. Failure to do this will result in a 10-20ps loss of skew margin (propagation delay) in the output(s) in use.

The MC100LVEP210, as with most other LVECL devices, can be operated from a positive V_{CC} supply in LVPECL mode. This allows the LVEP210 to be used for high performance clock distribution in +3.3V or +2.5V systems. Single ended input operation is limited to a $VCC \ge 3.0V$ in PECL mode, or $VEE \le -3.0V$ in ECL mode.

Designers can take advantage of the LVEP210's performance to distribute low skew clocks across the backplane or the board. In a LVPECL environment, series or Thevenin line terminations are typically used as they require no additional power supplies. For more information on using PECL, designers should refer to Application Note AN1406/D.

- 100ps Part-to-Part Skew
- 35ps Output-to-Output Skew
- Differential Design
- V_{BB} Output
- 475ps Typical Propagation Delay
- High Bandwidth to 1.5GHz Typical
- LVPECL and HSTL mode: 2.375V to 3.8V V_{CC} with V_{EE} = 0V
- LVECL mode: 0V V_{CC} with $V_{EE} = -2.375 V$ to -3.8 V
- Internal Input Resistors: Pulldown on D, \overline{D}
- Pullup and Pulldown on CLK
- ESD Protection: >2KV HBM, >100V MM
- Moisture Sensitivity Level 2
 For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 461 devices



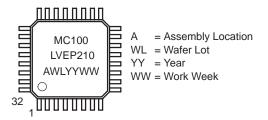
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32-LEAD TQFP FA SUFFIX CASE 873A

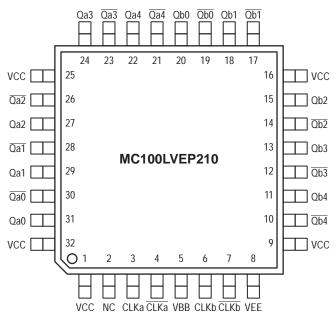
MARKING DIAGRAM*



*For additional information, see Application Note AND8002/D

ORDERING INFORMATION

Device	Package	Shipping
MC100LVEP210FA	TQFP	250 Units/Tray
MC100LVEP210FAR2	TQFP	2000 Tape & Reel



PIN DESCRIPTION										
PIN	FUNCTION									
CLKn/CLKn	LVECL/LVPECL/HSTL CLK Inputs									
Qn0:4/Qn0:4	LVECL/LVPECL Outputs									
VBB	Reference Voltage Output									
VCC	Positive Supply									
VEE	Negative, 0 Supply									

Figure 1. 32-Lead TQFP Pinout (Top View)

Warning: All V_{CC} and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation.

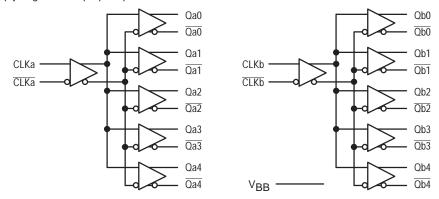


Figure 2. Logic Symbol

MAXIMUM RATINGS*

Symbol	Parameter		Value	Unit
VEE	Power Supply (V _{CC} = 0V)		-6.0 to 0	VDC
Vcc	Power Supply (V _{EE} = 0V)		6.0 to 0	VDC
VI	Input Voltage (V _{CC} = 0V, V _I not more negative than V _{EE})		-6.0 to 0	VDC
VI	Input Voltage (V _{EE} = 0V, V _I not more positive than V _{CC})		6.0 to 0	VDC
l _{out}	· ·	nuous Surge	50 100	mA
I _{BB}	V _{BB} Sink/Source Current†		± 0.5	mA
TA	Operating Temperature Range		-40 to +85	°C
T _{stg}	Storage Temperature		-65 to +150	°C
θJA	,	Still Air OOlfpm	80 55	°C/W
θЈС	Thermal Resistance (Junction-to-Case)		12 to 17	°C/W
T _{sol}	Solder Temperature (<2 to 3 Seconds: 245°C desired)		265	°C

^{*} Maximum Ratings are those values beyond which damage to the device may occur.

[†] Use for inputs of same package only.

DC CHARACTERISTICS, ECL/LVECL ($V_{CC} = 0V$; $V_{EE} = -3.3(+0.925, -0.5)V$) (Note 5.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
IEE	Power Supply Current (Note 1.)	60	70	90	60	70	90	60	70	90	mA
Vон	Output HIGH Voltage (Note 2.)	-1145	-1020	-895	-1145	-1020	-895	-1145	-1020	-895	mV
VOL	Output LOW Voltage (Note 2.)	-1995	-1820	-1650	-1995	-1820	-1650	-1995	-1820	-1650	mV
VIH	Input HIGH Voltage Single Ended	-1165		-880	-1165		-880	-1165		-880	mV
VIL	Input LOW Voltage Single Ended	-1810		-1475	-1810		-1475	-1810		-1475	mV
V_{BB}	Output Voltage Reference (Note 3.)	-1525	-1425	-1325	-1525	-1425	-1325	-1525	-1425	-1325	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Note 4.)	VEE	+1.2	0.0	VEE	+1.2	0.0	VEE	+1.2	0.0	V
lн	Input HIGH Current			150			150			150	μΑ
IIL	Input LOW Current CLK CLK	0.5 -150			0.5 -150			0.5 -150			μА

NOTE: 100EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

1. V_{CC} = 0V, V_{EE} = V_{EEmin} to V_{EEmax}, all other pins floating.

2. All loading with 50 ohms to V_{CC}-2.0 volts.

3. Single ended input operation is limited V_{EE} ≤ -3.0V in ECL/LVECL mode.

- 4. VIHCMR min varies 1:1 with VEE, max varies 1:1 with VCC.
- 5. Input and output parameters vary 1:1 with V_{CC}.

DC CHARACTERISTICS, LVPECL (V_{CC} = 3.3V \pm 0.5V, V_{EE} = 0V) (Note 10.)

			–40°C		25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
IEE	Power Supply Current (Note 6.)	60	70	90	60	70	90	60	70	90	mA
VOH	Output HIGH Voltage (Note 7.)	2155	2280	2405	2155	2280	2405	2155	2280	2405	mV
VOL	Output LOW Voltage (Note 7.)	1305	1480	1650	1305	1480	1650	1305	1480	1650	mV
VIH	Input HIGH Voltage Single Ended	2135		2420	2135		2420	2135		2420	mV
V _{IL}	Input LOW Voltage Single Ended	1490		1825	1490		1825	1490		1825	mV
V _{BB}	Output Voltage Reference (Note 8.)	1775	1875	1975	1775	1875	1975	1775	1875	1975	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Note 9.)	1.2		3.3	1.2		3.3	1.2		3.3	V
lн	Input HIGH Current			150			150			150	μΑ
IIL	Input LOW Current CLK CLK	0.5 -150			0.5 -150			0.5 -150			μА

NOTE: 100EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

- 6. V_{CC} = 3.3V \pm 0.5V, V_{EE} = 0V, all other pins floating. 7. All loading with 50 ohms to V_{CC} =2.0 volts.
- 8. Single ended input operation is limited $V_{CC} \ge -3.0V$ in PECL mode. 9. V_{IHCMR} min varies 1:1 with V_{EE} , max varies 1:1 with V_{CC} . 10. Input and output parameters vary 1:1 with V_{CC} .

DC CHARACTERISTICS, LVEPECL ($V_{CC} = 2.5V \pm 0.125V$, $V_{EE} = 0V$) (Note 14.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
IEE	Power Supply Current (Note 11.)	60	70	90	60	70	90	60	70	90	mA
VOH	Output HIGH Voltage (Note 12.)	1355	1480	1605	1355	1480	1605	1355	1480	1605	mV
VOL	Output LOW Voltage (Note 12.)	505	680	850	505	680	850	505	680	850	mV
VIH	Input HIGH Voltage Single Ended	1335		1620	1335		1620	1335		1620	mV
VIL	Input LOW Voltage Single Ended	690		1025	690		1025	690		1025	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Note 13.)	1.2		2.5	1.2		2.5	1.2		2.5	V
ΊΗ	Input HIGH Current			150			150			150	μΑ
IIL	Input LOW Current CLK CLK	0.5 -150			0.5 -150			0.5 -150			μА

NOTE: 100EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

- 11. V_{CC} = 2.5V, V_{EE} = 0V, all other pins floating. 12. All loading with 50 ohms to V_{EE} . 13. V_{IHCMR} min varies 1:1 with V_{EE} , max varies 1:1 with V_{CC} . 14. Input and output parameters vary 1:1 with V_{CC} .

DC CHARACTERISTICS, HSTL ($V_{CC} = 2.5(-0.125, +1.3)V$, $V_{EE} = 0V$)

			–40°C		25°C		85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
VIH	Input HIGH Voltage				1200						mV
V _{IL}	Input LOW Voltage						400				mV
V ₉₆	Input Crossover Voltage				680		900				mV
Icc	Power Supply Current (Note 15.)		100			100			100		mA

^{15.} V_{CC} = 2.375V to 3.8V, V_{EE} = 0V, all other pins floating.

AC CHARACTERISTICS ($V_{CC} = 0V$; $V_{EE} = -2.5V$ to -3.8V) or ($V_{CC} = 2.5V$ to 3.8V; $V_{EE} = 0V$)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
fmaxLVPECL	Maximum Toggle Frequency for LVECL and LVPECL (Note 16.)					1.5					GHz
fmaxHSTL	Maximum Toggle Frequency for HSTL (Note 16.)					250					MHz
tPLH, tPHL	Propagation Delay Differential	200	300	400	200	350	450	300	500	750	ps
tSKEW	Within Device Skew Duty Cycle Skew (Note 17.)		TBD TBD			25 100	35		TBD TBD		ps
[†] JITTER	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
V _{PP}	Input Voltage Swing (Diff.)	150	800	1200	150	800	1200	150	800	1200	mV
t _r t _f	Output Rise/Fall Times Q (20% – 80%)	100	170	270	100	180	290	100	280	350	ps

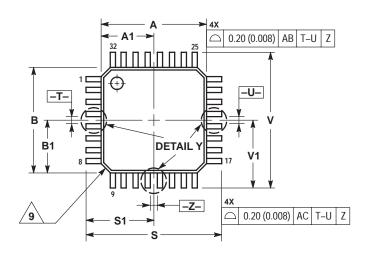
^{16.} F_{max} guaranteed for functionality only.

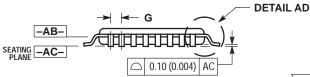
^{17.} Skew is measured between outputs under identical transitions of similar paths through a device. Duty cycle skew is defined only for differential operation when the delays are measured from the crosspoint of the inputs to the crosspoint of the outputs.

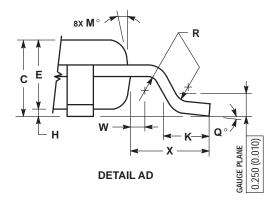
PACKAGE DIMENSIONS

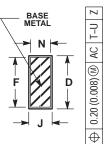
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32-LEAD PLASTIC PACKAGE CASE 873A-02 ISSUE A

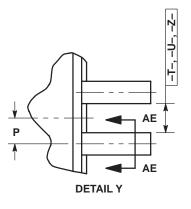








SECTION AE-AE



NOTES:

- 11. DIMENSIONING AND TOLERANCING PER ANSI
 Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DATUM PLANE -AB- IS LOCATED AT BOTTOM
 OF LEAD AND IS COINCIDENT WITH THE LEAD
 WHERE THE LEAD EXITS THE PLASTIC BODY AT
 THE BOTTOM OF THE PARTING LINE.
 4. DATUMS -T., -U., AND -Z. TO BE
 DETERMINED AT DATUM PLANE -AB-.
 5. DIMENSIONS S AND Y TO RE DETERMINED AT
 5. DIMENSIONS S AND Y TO RE DETERMINED AT

- DE TERMINED AT DATUM PLANE AB-.

 5. DIMENSIONS S AND V TO BE DETERMINED AT SEATING PLANE AC-.

 6. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.250 (0.010) PER SIDE. DIMENSIONS A AND B
- DO INCLUDE MOLD MISMATCH AND ARE
 DETERMINED AT DATUM PLANE -AB-.
 TO DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. DAMBAR PROTRUSION SHALL NOT CAUSE THE D DIMENSION TO EXCEED 0.520 (0.020).
- U.S.Z. (U.U.Z.).

 8. MINIMUM SOLDER PLATE THICKNESS SHALL BE 0.0076 (0.0003).

 9. EXACT SHAPE OF EACH CORNER MAY VARY FROM DEPICTION.

	MILLIN	METERS	INC	HES			
DIM	MIN	MAX	MIN	MAX			
Α	7.000	BSC	0.276 BSC				
A1	3.500	BSC	0.138	BSC			
В	7.000	BSC	0.276	BSC			
B1	3.500	BSC	0.138	BSC			
С	1.400	1.600	0.055	0.063			
D	0.300	0.450	0.012	0.018			
Ε	1.350	1.450	0.053	0.057			
F	0.300	0.400	0.012	0.016			
G	0.800	BSC	0.031	BSC			
Н	0.050	0.150	0.002	0.006			
J	0.090	0.200	0.004	0.008			
K	0.500	0.700	0.020	0.028			
M	12°	REF	12° REF				
N	0.090	0.160	0.004	0.006			
P	0.400		0.016	BSC			
Q	1°	5°	1°	5°			
R	0.150	0.250	0.006	0.010			
S	9.000	BSC	0.354	BSC			
S1	4.500	BSC	0.177	BSC			
V	9.000	BSC	0.354 BSC				
V1	4.500	BSC	0.177	BSC			
W	0.200	REF	0.008 REF				
Х	1.000	REF	0.039	REF			



Notes

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